FFPF30UA60S

Ultrafast II Diode 30 A, 600 V

Description

The FFPF30UA60S is a ultrafast II diode with low forward voltage drop. This device is intended for use as freewheeling and clamping diodes in a variety of switching power supplies and other power switching applications. It is specially suited for use in switching power supplies and industrial application.

Features

- Ultrafast Recovery, $t_{RR} = 90 \text{ ns}$ (@ $I_F = 30 \text{ A}$)
- Max Forward Voltage, $V_F = 2.2 \text{ V}$ (@ $T_C = 25^{\circ}\text{C}$)
- 600 V Reverse Voltage and High Reliability
- Avalanche Energy Rated
- This Device is Pb-Free and is RoHS Compliant

Applications

- Boost Diode in PFC and SMPS
- Welder, UPS and Motor Control Application

ABSOLUTE MAXIMUM RATINGS

T_C = 25°C unless otherwise noted

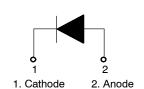
Symbol	Parameter	Rating	Unit	
Vrrm	Peak Repetitive Reverse Voltage	600	V	
VRWM	Working Peak Reverse Voltage	600	V	
lF(AV)	$I_{F(AV)}$ Average Rectified Forward Current @ $T_C = 43^{\circ}C$			
IFSM	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	180	Α	
ТЈ, Тѕтс	Operating Junction and Storage Temperature	- 65 to +175	°C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



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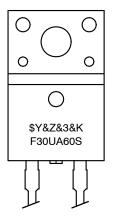
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TO-220, 2-Lead CASE 221AS

MARKING DIAGRAM



\$Y = ON Semiconductor Logo &Z&3 = Data Code (Year & Week)

&K = Lot

F30UA60S = Specific Device Code

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

FFPF30UA60S

THERMAL CHARACTERISTICS $T_C = 25^{\circ}C$ unless otherwise noted

Syn	nbol	Parameter	Max.	Unit
Re	∍JC	Maximum Thermal Resistance, Junction to Case	2.5	°C/W

PACKAGE MARKING AND ORDERING INFORMATION

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FFPF30UA60S	F30UA60S	TO-220F-2L	Tube	N/A	N/A	50

ELECTRICAL CHARACTERISTICS $T_C = 25^{\circ}C$ unless otherwise noted

Parameter	Conditions		Min.	Тур.	Max.	Unit
V _F (Note 1)	I _F = 30 A I _F = 30 A	T _C = 25°C T _C = 125°C	- -	- -	2.2 2.0	V
I _R (Note 1)	V _R = 600 V V _R = 600 V	T _C = 25°C T _C = 125°C	- -	- -	100 150	μΑ
t _{RR} I _{RR} Q _{RR}	$I_F = 30 \text{ A, } di_F/dt = 200 \text{ A/}\mu\text{s}$	T _C = 25°C	- - -	- - -	90 8 360	ns A nC
W _{AVL}	Avalanche Energy (L = 40 mH)		20	_	_	mJ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Test Circuit and Waveforms

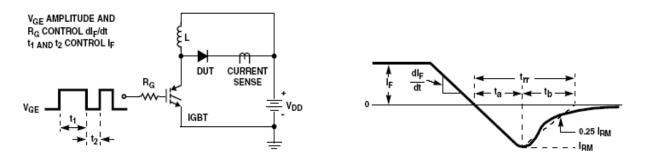


Figure 1. Diode Reverse Recovery Test Circuit & Waveform

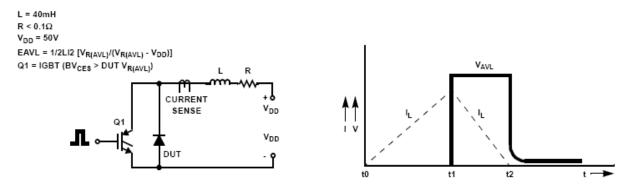


Figure 2. Unclamped Inductive Switching Test Circuit & Waveform

^{1.} Pulse: Test Pulse Width = 300 μs, Duty Cycle = 2%

FFPF30UA60S

TYPICAL PERFORMANCE CHARACTERISTICS

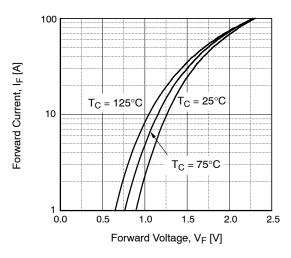


Figure 3. Typical Forward Voltage Drop vs. Forward Current

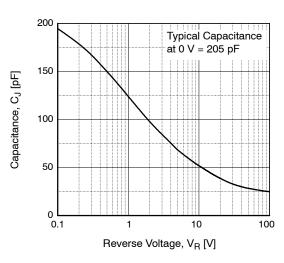


Figure 5. Typical Junction Capacitance

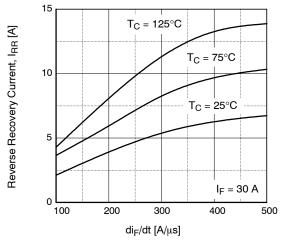


Figure 7. Typical Reverse Recovery Current vs. di_F/dt

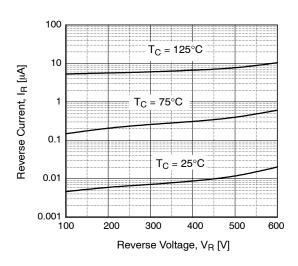


Figure 4. Typical Reverse Current vs. Reverse Voltage

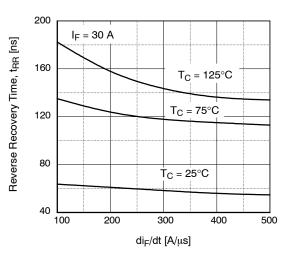


Figure 6. Typical Reverse Recovery Time vs. di_F/dt

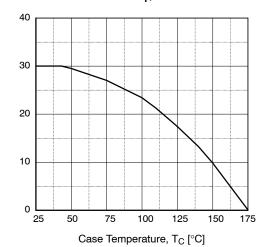
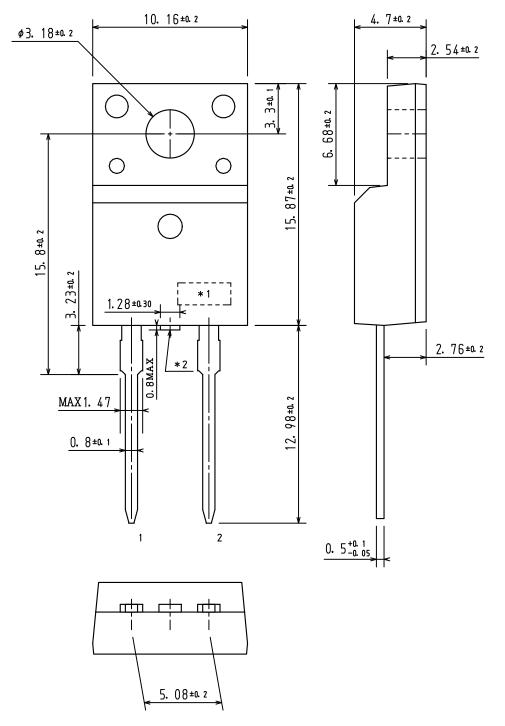


Figure 8. Forward Current Derating Curve

Average Forward Current, I_{F(AV)} [A]

TO-220 Fullpack, 2-Lead / TO-220F-2FS CASE 221AS ISSUE O

DATE 29 FEB 2012



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